

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/577,216	11/28/2006	Yuankai Zheng	2609-0008	3351
42624 DAVIDSON F	7590 01/28/2008 BERQUIST JACKSON & C	OWDEY LLP	LAM, DAVID ART UNIT PAPER NUMBER	
4300 WILSON	BLVD., 7TH FLOOR			
ARLINGTON	, VA ⁻ 22203			
			2827	
		•		
		·	MAIL DATE	DELIVERY MODE
			01/28/2008	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

•)	Application No.	Applicant(s)			
	10/577,216	ZHENG ET AL.			
Office Action Summary	Examiner	Art Unit			
	David Lam	2827			
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet wi	th the correspondence address	,		
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period we Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a rewrithin the statutory minimum of thirt will apply and will expire SIX (6) MON cause the application to become AB	eply be timely filed y (30) days will be considered timely. THS from the mailing date of this communicat ANDONED (35 U.S.C. § 133).	ion.		
Status					
1) Responsive to communication(s) filed on					
2a) This action is FINAL . 2b) This	action is non-final.	•			
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under E	x parte Quayle, 1935 C.D	. 11, 453 O.G. 213.			
Disposition of Claims	,				
4) Claim(s) 1-26 is/are pending in the application.					
4a) Of the above claim(s) is/arè withdraw					
5) Claim(s) 1-26 is/are allowed.					
6) Claim(s) is/are rejected.					
7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and/or	r election requirement.				
Application Papers					
9) The specification is objected to by the Examine	r.				
10) The drawing(s) filed on is/are: a) acce	epted or b) objected to	by the Examiner.			
Applicant may not request that any objection to the	drawing(s) be held in abeyan	ce. See 37 CFR 1.85(a).			
Replacement drawing sheet(s) including the correcti		•			
11) The oath or declaration is objected to by the Ex	aminer. Note the attached	Office Action or form PTO-152.			
Priority under 35 U.S.C. § 119					
12) ☐ Acknowledgment is made of a claim for foreign a) ☐ All b) ☐ Some * c) ☐ None of:	priority under 35 U.S.C. §	119(a)-(d) or (f).			
1. Certified copies of the priority documents	s have been received.				
2. Certified copies of the priority documents					
3. Copies of the certified copies of the prior	•	received in this National Stage			
application from the International Bureau * See the attached detailed Office action for a list of	• • • • • • • • • • • • • • • • • • • •	received			
See the attached detailed Office action for a list of	of the certified copies not	received.			
Attachment(s)		•			
1) Motice of References Cited (PTO-892)	<i>,</i>	ummary (PTO-413)			
2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08))/Mail Date formal Patent Application (PTO-152)			
Paper No(s)/Mail Date <u>4/26/06, 7/18/06</u> .	6) Other:				

Application/Control Number: 10/577,216

Art Unit: 2827

DETAILED ACTION

This application is in condition for allowance except for the following formal matters:

IN THE SPECIFICATION:

Applicant is reminded of the proper language and format for an abstract of the disclosure.

The abstract should be in narrative form and generally limited to a single paragraph on a separate sheet within the range of 50 to 150 words. It is important that the abstract not exceed 150 words in length since the space provided for the abstract on the computer tape used by the printer is limited. The form and legal phraseology often used in patent claims, such as "means" and "said," should be avoided. The abstract should describe the disclosure sufficiently to assist readers in deciding whether there is a need for consulting the full patent text for details.

The language should be clear and concise and should not repeat information given in the title. It should avoid using phrases which can be implied, such as, "The disclosure concerns," "The disclosure defined by this invention," "The disclosure describes," etc.

IN THE CLAIM:

- In claim 9, line 1, "as claimed in claim" should be change to -- as claimed in claim 1 --.

Allowable Subject Matter

Claims 1-26 are allowable over the prior art of record because none of the prior art whether taken singularly or in combination, especially when these limitations are considered within the specific combination claimed, to teach: a magnetoresistive random access memory (MRAM) comprising: a plurality of transistors formed on a substrate; a plurality of active areas defined in a common memory block comprising a ferromagnetic recording layer, a free magnetic reading layer, a non-magnetic space layer between the ferromagnetic recording layer and the free magnetic reading layer; a plurality of contacts, in combination with others as claimed in

Application/Control Number: 10/577,216

Art Unit: 2827

independent claim 1, each of the plurality of contacts electrically connecting a respective on of the first source/drain electrodes with a corresponding on the plurality of active area, wherein each of the plurality of transistor is controllable to electrically activate a corresponding one of the plurality of contacts and thereby to write/read a data bit into/from the ferromagnetic recording layer as a respective on of the effective magnetoresistive element. Method of writing data in a MRAM comprising steps of raising the temperature of a ferromagnetic recording layer; writing a magnetization state representing a bit of the data in the ferromagnetic recording layer at the effective magnetoresistive element by passing a current through a common digital line, and in combination with others as claimed in independent claim 19. Method of reading data from a MRAM comprising step of determining the magnetization state of the ferromagnetic recording layer at the effective magnetoresistive element, wherein the resistance states of the ferromagnetic recording layer at the effective magnetoresistive element are dependent on the relative angles between the magnetization vectors of the ferromagnetic recording layer at the effective magnetoresistive element and the free magnetic reading layer, and in combination with others as claimed in independent claim 25.

Conclusion

Prosecution on the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

A shortened statutory period for reply to this action is set to expire **TWO MONTHS** from the mailing date of this letter.

Application/Control Number: 10/577,216

Art Unit: 2827

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

- Hoenigschmid et al. (6,944,049) disclose magnetic tunnel junction memory cell architecture.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to David Lam whose telephone number is 571-272-1782. The examiner can normally be reached on 6:00-4:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Amir Zarabian can be reached on 571-272-1852. The fax phone numbers for the organization where this application or proceeding is assigned is (571) 273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/David Lam/ AU 2827

January 17, 2008

DAVID LAM
PRIMARY EXAMINER